# 4V Drive Pch MOSFET RSR025P03

#### ●Structure

Silicon P-channel MOSFET

#### ● Features

- 1) Low On-resistance
- 2) Space saving-small surface mount package (TSMT3)
- 3) 4V drive

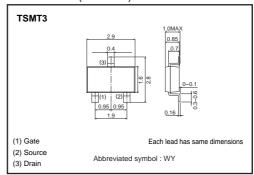
# Applications

Switching

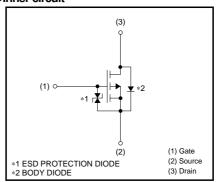
## Packaging specifications

	Package	Taping	
Type	Code	TL	
	Basic ordering unit (pieces)	3000	
RSR025P03		0	

## ●Dimensions (Unit:mm)



#### •Inner circuit



## ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		$V_{DSS}$	-30	V
Gate-source voltage		V <sub>GSS</sub>	±20	V
Drain current	Continuous	$I_D$	±2.5	Α
Drain current	Pulsed	I <sub>DP</sub> *1	±10	Α
Source current	Continuous	Is	-0.8	Α
(Body diode)	Pulsed	I <sub>SP</sub> *1	-10	Α
Total power dissipation		P <sub>D</sub> *2	1	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

<sup>\*1</sup> Pw≤10μs, Duty cycle≤1% \*2 Mounted on a ceramic board

## ●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	125	°C/W

<sup>\*</sup> Mounted on a ceramic board

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	1	-	±10	μΑ	Vgs=±20V, Vps=0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	-30	_	_	V	I <sub>D</sub> = -1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	IDSS	_	_	-1	μΑ	V <sub>DS</sub> = -30V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	-1.0	_	-2.5	V	$V_{DS}$ = -10V, $I_{D}$ = -1mA
Static drain-source on-state resistance		-	70	98	mΩ	I <sub>D</sub> = -2.5A, V <sub>G</sub> S= -10V
	R <sub>DS (on)</sub> *	-	100	140	mΩ	I <sub>D</sub> = -1.2A, V <sub>G</sub> S= -4.5V
		-	115	160	mΩ	I <sub>D</sub> = -1.2A, V <sub>G</sub> S= -4V
Forward transfer admittance	Y <sub>fs</sub>   *	1.6	_	_	S	V <sub>DS</sub> = -10V, I <sub>D</sub> = -1.2A
Input capacitance	Ciss	-	460	_	pF	V <sub>DS</sub> = -10V
Output capacitance	Coss	_	105	_	pF	Vgs=0V
Reverse transfer capacitance	Crss	_	65	_	pF	f=1MHz
Turn-on delay time	t <sub>d (on)</sub> *	_	10	_	ns	V <sub>DD</sub> ≒ −15V
Rise time	tr *	_	10	_	ns	ID= -1.2A
Turn-off delay time	td (off) *	_	42	_	ns	V <sub>GS</sub> = −10V R <sub>L</sub> =12.5Ω
Fall time	t <sub>f</sub> *	_	10	_	ns	Rgs=10Ω
Total gate charge	Qg *	_	5.4	_	nC	V <sub>DD</sub> ≒-15V V <sub>GS</sub> =-5V
Gate-source charge	Q <sub>gs</sub> *	_	1.4	_	nC	I <sub>D</sub> = -2.5A
Gate-drain charge	Q <sub>gd</sub> *	_	1.6	_	nC	R <sub>L</sub> =6Ω R <sub>G</sub> =10Ω

\*Pulsed

# ●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp	-	_	-1.2	V	I <sub>S</sub> = -0.8A, V <sub>GS</sub> =0V

#### Electrical characteristic circuits

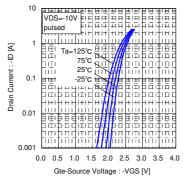


Fig.1 Typical Transfer Characteristics

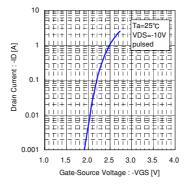


Fig.2 Typical Transfer Characteristics

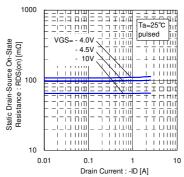


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

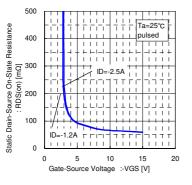


Fig.4 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

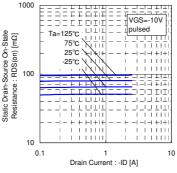


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

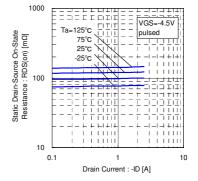


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

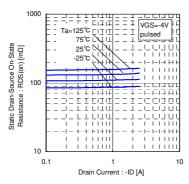


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current

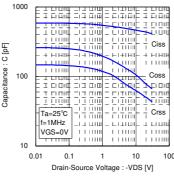


Fig.8 Typical Capacitance vs. Drain-Source Voltage

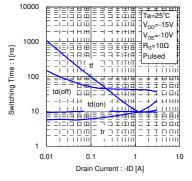
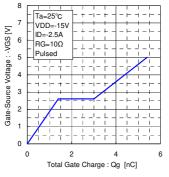
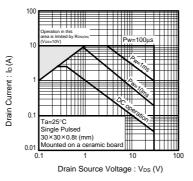


Fig.9 Switching Characteristics





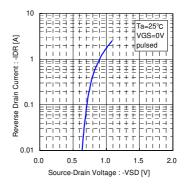


Fig.10 Dynamic Input Characteristics

Fig.11 Safe operating area

Fig.12 Reverse Drain Current vs. Source-Drain Voltage

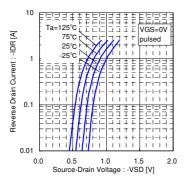


Fig.13 Reverse Drain Current vs. Source-Drain Voltage

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